

- ⊗ Wavelength: 860+/-10 nm
- ⊗ Output Power: Up to 3000mW free space / 2400mW fiber coupled
- ⊗ High output power and high efficiency
- ⊗ Proven reliability
- ⊗ Custom packaging available
- ⊗ Custom wavelengths and laser designs are available.



The LDX-3310-860 is a high-power laser diode chip. Designed for low divergence and high brightness, and offers proven reliability. This chip is used in a wide range of applications in the medical, industrial, research, and military markets.

These lasers are available in the following free space and fiber-coupled packages:

C-mount, B-mount, COS, 9mm, 9mm Isolated, TO3, HHL, 9mm SMA, FCP (2 Pin), HHLFC, and custom package options.

### Device Specifications (Specified values are at rated power at 25° on a C-mount)

Parameter	LDX-3310-860	Units
Output Power	3,000	mW
Wavelength	860	+/-10 nm
Spectral Width	3	nm
Operating Temperature	25	°C
Aperture Size	100	um
Operating Current	2,810	mA
Threshold Current	405	mA
Slope Efficiency	1.20	W/A
Forward Voltage	1.7	V
Fast Axis Divergence	36	° (FWHM)
Slow Axis Divergence	7	° (FWHM)
Polarization	TE	N/A
Fiber Size HHL, BTF, FCP <sup>1</sup>	105 or 200	um
Min. Fiber Size 9mm SMA <sup>2</sup>	250	um
Expected Lifetime <sup>3</sup>	>10,000	Hours (EOL) <sup>4</sup>

Unless otherwise indicated, all values are nominal.

1. Other fiber diameters are available upon requested.
2. If minimum fiber size is used, a high power SMA connector is required.
3. Lifetime is greatly affected by Package type, Operating temperature, Thermal resistance, Operation (CW vs Off/On), and Packaging stress
4. End of Life (EOL) is defined as when the operating current must be increased by >20% to maintain the Beginning of Life (BOL) optical output power.

LDX follows a policy of continuous product improvement.  
**Specifications are subject to change without notice.**

These components do not comply with the Federal Regulations (21 CFR Subchapter 1) as administered by the Center for Devices and Radiological health. Purchaser acknowledges that his/her products must comply with these regulations before they can be sold to a customer



**Free Space Package - Exposed Emitter**

Package		Features	Options	Drawing
C-Mount Package		Small footprint with screw mounting Material – Copper (OFHC) Fast-axis lensing	Fast-axis lensing	
B-Mount Package		Very small footprint Requires soldering to heatsink Material – Copper Tungsten (CuW)	Fast-axis lensing	
Chip-on-Submount		Very small footprint Requires soldering to heatsink Material – BeO	Fast-axis lensing	

**Free Space Package - Hermetically Sealed Windowed Packages**

Package		Features	Options	Drawing
9mm Package		Industry-standard package Header material – Copper	Photodiode, Isolated package, Fast-axis lensing	
TO-3 Package		Mounting to heatsink with screws Header material – Copper	TEC, Thermistor, Photodiode, Fast-axis lensing	
HHL Package		Internal peltier cooler (TEC), thermistor, and photodiode Header material – Copper	Fast-axis lensing	

**FAC Lensing Options:**

Best Collimation	L1	Less than 1° divergence in the fast axis direction.
Squared Beam FAC	L2	Matches the fast-axis to the slow-axis divergence.

**Fiber Coupled Packages - Hermetically Sealed - >80% Coupling Efficiency**

Package		Features	Options	Drawing
9mm SMA FC Package		Industry-standard package SMA connector for detachable fiber Header material – Copper	Photodiode, Isolated package	
8-Pin BFC Package		Built-in internal TEC and Photodiode Fiber pigtail with SMA connector Header material – Copper	Thermistor	
2-Pin FCP Package		Fiber pigtail with SMA connector Header material – Copper	none	
HHL-FC Package		Fiber pigtail with SMA connector Internal peltier cooler (TEC), thermistor, and photodiode Header material – Copper	none	

**Part Numbering System**

Part Number	Description
LDX-3115-680-9	Semiconductor Laser Diode, 680±3 nm, 1200mW, 150um emitter, 9mm Package
LDX-2405-690-BFC-105	Semiconductor Laser Diode, 690±3 nm, 400mW, 50um emitter, Pigtailed Fiber Coupled 8-pin BFC Package w/ >80% Output Power from Fiber, Includes 105um, 0.22NA, 1m long fiber pigtail with SMA connector
LDX-2410-645-B-L1	Semiconductor Laser Diode, 645±5 nm, 400mW, 100um emitter, B-mount w/ FAC Lensing, Best Collimation
LDX-2710-660-HHL-L2	Semiconductor Laser Diode, 660±3 nm, 750mW, 100um emitter, HHL Package w/ TEC, PD, Thermistor, FAC Lens, Squared Beam

  

LDX-XXXX-XXX-XXX-XXX
<p>LDX Optronics</p> <p>Chip Design</p> <p>Wavelength</p> <p>Package Type</p> <ul style="list-style-type: none"> <li>C – C-Mount</li> <li>B – B-Mount</li> <li>Q – Q-Mount</li> <li>CO5 – Chip on Submount</li> <li>9 – 9mm Package</li> <li>TO3 – TO-3 Package</li> <li>HHL – HHL Package</li> <li>9-SMA – 9mm SMA Package</li> <li>HHL-FC – HHL Package</li> <li>BFC – 8 pin High Heat Load</li> <li>FCP – 2-pin Package</li> <li>CHIP – Unmounted Chip</li> <li>BAR – Unmounted Bar</li> </ul> <p>Options</p> <ul style="list-style-type: none"> <li>TEC – Internal TEC</li> <li>PD – Photodiode</li> <li>T – Thermistor</li> <li>L1 - FAC Lens, Best Collimation</li> <li>L2 - FAC Lens, Squared Beam</li> <li>AR – Low AR Coating</li> </ul>

For all handling and mounting precautions, see the [LDX Catalog](#)